

CTMLP100804BF

Series

From 0.47 μ H to 4.7 μ H



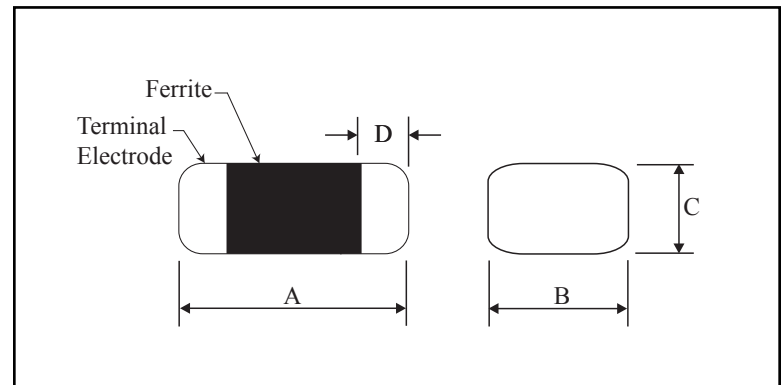
SPECIFICATIONS

Please specify tolerance code when ordering.
CTMLP100804BF-R47_ ← M = \pm 20%, N = \pm 30%

Part Number	Inductance (μ H)	Test Frequency	DCR \pm 25% (Ω)	Isat Max. (mA)	Irms Max. (mA)
CTMLP100804BF-R47_	0.47	3.0MHz, 200mV	0.04	1500	1800
CTMLP100804BF-1R0_	1.0	3.0MHz, 200mV	0.055	900	1600
CTMLP100804BF-1R5_	1.5	3.0MHz, 200mV	0.07 \pm 30%	800	1400
CTMLP100804BF-2R2_	2.2	3.0MHz, 200mV	0.08	500	1300
CTMLP100804BF-3R3_	3.3	3.0MHz, 200mV	0.10	400	1200
CTMLP100804BF-4R7_	4.7	3.0MHz, 200mV	0.11	300	1100

PHYSICAL DIMENSIONS

Size	A	B	C Max.	D
mm	2.5 \pm 0.20	2.0 \pm 0.20	1.00	0.6 \pm 0.2
inches	0.098 \pm 0.008	0.079 \pm 0.008	0.039	0.024 \pm 0.008



CHARACTERISTICS

Description: SMD Multi-layer Power Chip Inductor. Magnetically shielded.

Applications: Cellular phones, Power modules, DC/DC converters, Digital cameras, DVD, Portable devices, etc.

Operating Temperature: -55°C to 125°C (including self - temp. rise).

Isat: Inductance drop 30% from its value with current.

Irms: 40°C temperature rise from 25°C ambient with current.

Inductance Tolerance: \pm 20% (M), \pm 30% (N)

Packaging: Tape & Reel.

Miscellaneous: **RoHS Compliant.**

Additional Information: Additional electrical & physical information available upon request.

Samples available. See website for ordering information.

PAD LAYOUT

